

Anharmonic effects in thermoelectric and 2D materials

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July 4, 2020



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General outline

- ① Thermoelectric monochalcogenides (part 1)
 - Bulk SnSe and SnS
 - Monolayer SnSe

- ② 2D materials (part 2)
 - Graphene

Outline

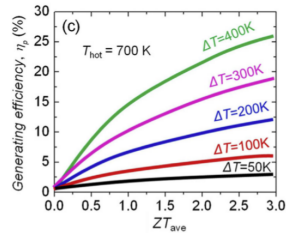
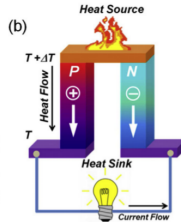
- Introduction
- Theoretical framework
- Part 1: Thermoelectric monochalcogenides
- Part 2: 2D materials
- Conclusions

Introduction

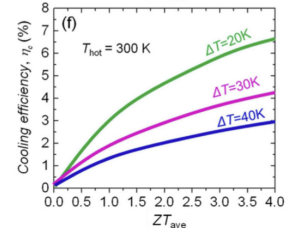
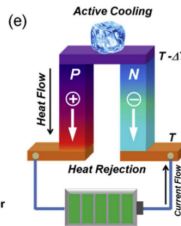
$$ZT = \frac{S^2 \sigma T}{\kappa}, \quad S = -\frac{\Delta V}{\Delta T}$$



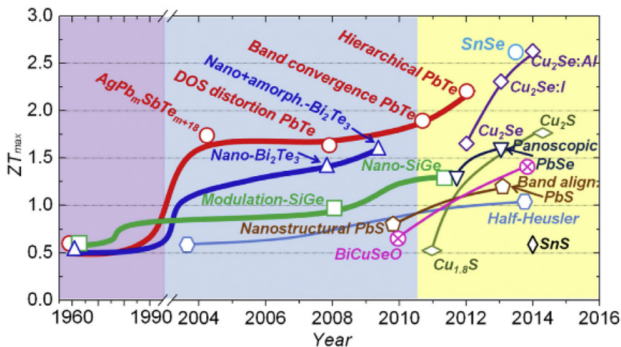
Thomas Johann Seebeck
German (1770-1831)



Jean Charles Athanase Peltier
French (1785-1845)



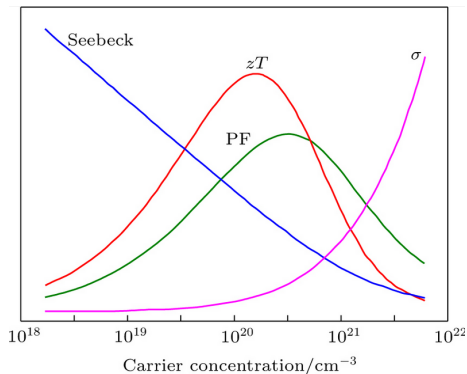
Introduction



- ZT_{max} low and in narrow temperature ranges
- Very limited technological applications.

X. Zhang, L-D. Zhao / Journal of Materiomics 1 (2015) 92-105

Introduction



- The physical magnitudes that define ZT are correlated
- How to overcome:
 - Doping + nanostructuring
 - Proximity to phase transitions
 - ...

Ultralow thermal conductivity and high thermoelectric figure of merit in SnSe crystals

Li-Dong Zhao¹, Shih-Han Lo², Yongsheng Zhang², Hui Sun³, Gangjian Tan¹, Citrad Uher³, C. Wolverton², Vinayak P. Dravid² & Mercouri G. Kanatzidis¹

The thermoelectric effect enables direct and reversible conversion between thermal and electrical energy, and provides a viable route for power generation from waste heat. The efficiency of thermoelectric materials is dictated by the dimensionless figure of merit, ZT (where Z is the figure of merit and T is absolute temperature), which governs the Carnot efficiency for heat conversion. Enhancements above the generally high threshold value of 2.5 have important implications for commercial deployment^{1,2}, especially for compounds free of Pb and Te. Here we report an unprecedented ZT of 2.6 ± 0.3 at 923 K, realized in SnSe single crystals measured along the b axis of the room-temperature orthorhombic unit cell. This material also shows a high ZT of 2.3 ± 0.3 along the c axis but a significantly reduced ZT of 0.8 ± 0.2 along the a axis. We attribute the remarkably high ZT along the b axis to the intrinsically ultralow lattice thermal conductivity in SnSe. The layered structure of SnSe derives from a distorted rock-salt structure, and features anomalously high Grüneisen parameters, which reflect the anharmonic and anisotropic bonding. We attribute the exceptionally low lattice thermal conductivity ($0.23 \pm 0.03 \text{ W m}^{-1} \text{ K}^{-1}$ at 973 K) in SnSe to the anharmonicity. These findings highlight alternative strategies to nanostructuring for achieving high thermoelectric performance.

power factor (along the b axis), but, even more surprisingly, we observe that the thermal conductivity of SnSe is intrinsically ultralow ($<0.25 \text{ W m}^{-1} \text{ K}^{-1}$ at $>800 \text{ K}$), resulting in $ZT = 2.62$ at 923 K along the b axis and 2.3 along the c axis; these represent the highest ZT values reported so far for any thermoelectric system. Along the a direction, however, ZT is significantly lower, ~ 0.8 . Here, it should be noted that SnSe along the b axis shows a room-temperature $ZT = 0.12$, which is comparable to the room-temperature value of 0.15 reported earlier¹⁹. SnSe, however, reveals high ZT values near and above the transition temperature of 750 K at which the structure converts from $Pnma$ to $Cmcm$ ^{20–22}. Such ultrahigh ZT along two principal directions and the observed crystallographic and ZT anisotropy prompted us to investigate the scientific underpinning of these intriguing results.

SnSe adopts a layered orthorhombic crystal structure at room temperature, which can be derived from a three-dimensional distortion of the NaCl structure. The perspective views of the room-temperature SnSe crystal structure along the a , b and c axial directions are shown in Fig. 1a–d. There are two-atom-thick SnSe slabs (along the b - c plane) with strong Sn–Se bonding within the plane of the slabs, which are then linked with weaker Sn–Se bonding along the a direction²⁰. The structure contains highly distorted SnSe₄ coordination polyhedra, which have

- The best thermoelectric material so far: Intrinsic semiconductor with low lattice thermal conductivity ($\kappa = \kappa_{el} + \kappa_l$)

Introduction

1	Chalcogenides																2	
H																	He	
3	4																	10
Li	Be																	Ne
11	12																	18
Na	Mg																	Ar
19	20	21	22	23	24	25	26	27	28	29	30	31	32	33	34	35	36	
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr	
37	38	39	40	41	42	43	44	45	46	47	48	49	50	51	52	53	54	
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	I	Xe	
55	56	*	72	73	74	75	76	77	78	79	80	81	82	83	84	85	86	
Cs	Ba		Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	Rn	
87	88	+	104	105	106	107	108	109	110	111	112	113	114	115	116	117	118	
Fr	Ra		Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg	Uub	Uut	Uuq	Uup	Uuh	Uus	Uuo	

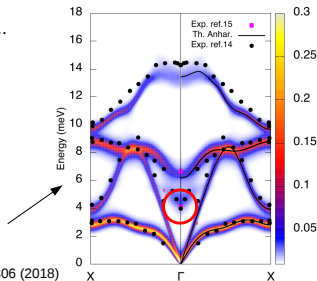
Chalcogenides

Monochalcogenides: PbTe, SnTe, GeTe, SnS...

Low lattice thermal conductivity

They show strongly anharmonic features:

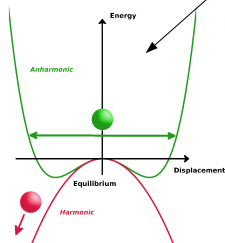
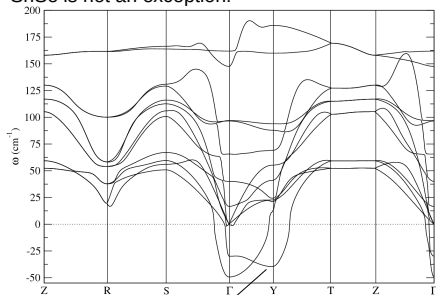
- Lattice instabilities in the harmonic phonons
- Ferroelectric transitions
- Incipient ferroelectricity
- Special features in the phonon spectral function



G. A. Ribeiro et al. Physical Review B 97, 014306 (2018)

Introduction

SnSe is not an exception:

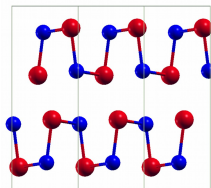
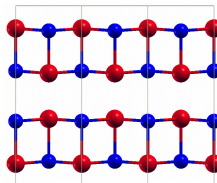


LATTICE INSTABILITIES

PHASE TRANSITION

$T_c = 800 \text{ K}$

High T
Cmcm



Low T
Pnma

Very low lattice thermal conductivity 0.3-1.0 W/mK (800 K)